I. Number	Hits 1	Search Text "20030015740"	DB USPAT;	Time stamp 2003/03/11 14:36
			US-PGPUB; EPO; JPO; DERWENT;	
2	13741	Jian Li.INV.	IBM_TDB USPAT. US-PGPUB; EPO; JPO;	2003/03/11 14:37
3	14149	intel.AS.	DI RWENT: IBM_TDB USPAT, US-PGPUB;	2003/03/11 14:37
1	64	intel AS and (Fan Li DW)	EPO; JPO; DERWENT; IBM_FDB	2002 02 11 11.27
4	04	intel.AS. and (Jian Li.INV.)	USPAT. US-PGPUB: EPO: JPO; DERWENT;	2003 03:11 14:37
5	3	(intel.AS. and (Jian Li.INV.)) and topology	IBM_FDB USPAT; US-PGPUB; EPO; JPO;	2003/03/11 14:59
6	113555	memory adj device	DERWENT; IBM_TDB USPAT; US-PGPUB;	2003/03/11 15:00
7	43429	bit adj line	EPO: JPO: DERWENT: IBM_TDB USPAT:	2003/03/11 15:01
8	38458	word adj line	US-PGPUB; EPO; JPO; DERWENT; IBM_TDB USPAT;	2003/03/11 15:04
			US-PGPUB: FPO: JPO: DERWENT:	2003/03/11 13:01
9	10847	(memory adj device) and (bit adj line) and (word adj line)	IBM_TDB USPAT; US-PGPUB; EPO; JPO;	2003/03/11 15:16
10	27654	topology	DERWENT; IBM_TDB USPAT; US-PGPUB; EPO; IPO;	2003/03/11 15:52
11	2249	self-aligned adj contact	DERWENT; IBM_TDB USPAT;	2003/03:11 15:53
12	.05		US-PGPUB; EPO; JPO; DERWENT; IBM_TDB	
12	687	buried adj bit adj line	USPAT; US-PGPUB; EPO: JPO; DERWENT;	2003 03 11 15:54
			IBM_TDB	

13	35	(self-aligned adj contact) and (buried adj bit adj line)	USPAT:	2003 03 11 16:23
			US-PGPUB; EPO; JPO; DERWENT;	
14	5	((self-aligned adj contact) and (buried adj bit adj line)) and damascene	IBM_TDB USPAT; US-PGPUB;	2003 03 11 15:56
15		((self-aligned adj contact) and (buried adj bit adj line)) and (not 14.)	EPO, JPO; DERWENT; IBM_TDB	
	0		USPAT; US-PGPUB; EPO, JPO;	2003/03/11 15:56
16	11	((self-aligned adj contact) and (buried adj bit adj line)) and CVD	DERWENT: IBM_TDB	2002/02/11 17:12
	11		USPAT; US-PGPUB; EPO, JPO;	2003/03/11 17:43
17	2	"20020135027"	DERWENT; IBM_TDB USPAT;	2003/03/11 17:52
			US-PGPUB; EPO, JPO; DERWENT;	
18	187537	seiko epson.AS.	IBM_TDB USPAT: US-PGPUB:	2003/03/11 17:53
			EPO; JPO; DERWENT;	
19	37	(seiko epson.AS.) and drain-drain	IBM_TDB USPAT; US-PGPUB;	2003/03/11 17:53
20	22	((seiko epson.AS.) and drain-drain) and SRAM	EPO; JPO; DERWENT; IBM_TDB	
	33		USPAT; US-PGPUB; EPO; JPO;	2003/03/11 18:16
21	27299	Thinh Nguyen.XA.	DERWENT; IBM_TDB USPAT;	2003/03/11 17:55
			US-PGPUB; EPO; JPO; DERWENT;	
22	206	(Thinh Nguyen.XA.) and (seiko epson.AS.)	IBM_TDB USPAT; US-PGPUB;	2003/03/11 17:55
			EPO; JPO; DERWENT; IBM_IDB	
23	0	((Thinh Nguyen,XA.) and (seiko epson,AS.)) and drain-drain	USPAT; US-PGPUB; EPO; JPO;	2003/03/11 17:56
24	90	((Thinh Nguyen.XA.) and (seiko epson.AS.)) and memory	DERWENT; IBM_TDB	2002/02/11 17 50
	70		USPAT; US-PGPUB; EPO; JPO;	2003/03/11 17:58
25	1964803	Thinh T Nguyen.XA	DERWENT: IBM_TDB USPAT;	2003 03 11 17:58
			US-PGPUB; EPO; JPO; DERWENT;	
Search H	istory 3 11 03 6	5:50:37 PM Page 2	IBM_TDB	

26	U	(Thinh adj nguyen).XA.	USPAT; US-PGPUB;	2003 03 11 17:59
27	13	Thinh adj nguyen	EPO; JPO; DERWENT; IBM_TDB USPAT; US-PGPUB; EPO; JPO;	2003 03 11 18:04
28	320	Thinh.XA.	DERWENT: IBM_TDB USPAT: US-PGPUB; EPO, JPO; DERWENT:	2003.03.11 18:00
29	2	(((Thinh Nguyen.XA.) and (seiko epson.AS.)) and memory) and Thinh.XA.	IBM_TDB USPAT: US-PGPUB: EPO, JPO: DERWENT:	2003/03 11 18:01
30	174054	257 \$.ccls.	IBM TDB USPAT; US-PGPUB; EPO; JPO; DERWENT;	2003:03:11 18:02
32	()	(Thinh.XA. and (seiko epson.AS.)) and 257/\$.ccls.	IBM_TDB USPAT; US-PGPUB; EPO; JPO; DERWENT;	2003/03/11 18:02
31	8	Thinh.XA. and (seiko epson.AS.)	IBM_IDB USPAT; US-PGPUB; EPO; JPO; DERWENT;	2003/03/11 18:02
33	0	Thinh adj T adj Nguyen	IBM_TDB USPAT; US-PGPUB; EPO; JPO; DERWENT;	2003/03/11 18:04
34	580	fourth adj conductive adj layer	IBM_TDB USPAT; US-PGPUB; EPO; JPO; DERWENT;	2003/03/11 18:17
35	61	(fourth adj conductive adj layer) and SRAM	IBM_TDB USPAT; US-PGPUB; EPO; JPO; DERWENT; IBM_TDB	2003/03/11 18:18